

Supplementary Material to the manuscript
**Comparative study of structural and electronic properties
of GaSe and InSe polytypes**

by J. Srour, M. Badawi, F. El Haj Hassan and A. Postnikov :
bibliography of experiments and previous calculations

TABLE I. Lattice parameters of GaSe from experiments

Phase	a (Å)	c (Å)	\bar{c} (Å)	Ref.	Year
β	3.755	15.94	7.97	1	1961
γ	3.755	23.92	7.973	1	1961
ε	3.755 ± 0.002	15.946 ± 0.003	7.973	2	1971
δ	3.755(3)	31.990(10)	7.998	3,4	1975
ε	3.755 ± 0.002	15.959 ± 0.012	7.980	5	1978
β	3.750(4)	15.995(7)	7.998	6	1988
β	3.74 ± 0.01	16.10 ± 0.05	8.05	7	1989
γ	3.7 ± 0.1	24.0 ± 0.8	8.0	7	1989
ε	3.7 ± 0.1	16.0 ± 0.5	8.0	7	1989
ε	3.743	15.919	7.960	8	1991
ε	3.753	15.91	7.96	9	2005
ε	3.7591	15.968	7.984	10	2007
ε	3.7384	16.0282	8.0141	11	2010

TABLE II. Optimized lattice parameters of GaSe from DFT calculations

Phase	a (Å)	c (Å)	\bar{c} (Å)	Method / XC	Ref.	Year
ε	3.724		7.839	DFPT / LDA	12	1998
ε	3.720	15.620	7.810	WIEN2k / LDA	13	2006
β	3.83	16.29	8.145	WIEN2k / PBE	14	2009
β	3.80	16.17	8.085	VASP / PBE	14	2009
ε	3.738	15.657	7.829	<i>ab init</i> / LDA	15	2010
ε	3.662	15.587	7.794	<i>ab init</i> / LDA	16	2011
β	3.830	16.393	8.197	WIEN2k / PBE	17	2013
ε	3.822	16.281	8.141	WIEN2k / PBE	17	2013
β or ε	3.751	15.948	7.974	VASP / PBE+D2	18	2013
ε	3.738	15.657	7.829	Quant.Espr. / LDA	19	2013
ε	3.839	17.151	8.576	Quant.Espr. / PBE	19	2013
ε	3.798	15.886	7.943	Quant.Espr. / vdW-DF2	19	2013
ε	3.743	15.919	7.965	Quant.Espr. / PBE+D2	19	2013
ε	3.711	15.67	7.835	CASTEP / LDA	20	2014
ε	3.72	15.74	7.87	Quant.Espr. / LDA	21	2014

TABLE III. Lattice parameters of InSe from experiments

Phase	a (Å)	c (Å)	\bar{c} (Å)	Ref.	Year
γ	4.00	24.85	8.283	22 ^a	1974
γ	4.00	25.32	8.44	23	1975
β	4.005(5)	16.640(4)	8.320	24	1979
γ	4.002(1)	24.946(6)	8.315	25	1980
γ	4.002(1)	24.946(6)	8.315	26	1981
β	4.00 ± 0.04	16.7 ± 0.2	8.35	27	1986
γ	4.00 ± 0.04	25.3 ± 0.3	8.43	27	1986
γ	4.002	24.946	8.315	28	2003
γ	4.002	24.961	8.32	29	2017

^aThis publication cites earlier works which we could not directly inspect: $a=4.023$ Å, $c=25.05$ Å for γ from Schubert+Dörre+Gunzel, *Naturw.* **41**, 448 (1954) and $a=4.05$ Å, $c=16.93$ Å for hexagonal phase (β ?) from Semiletov, *Kristallogr.* (1958), p.2988.

TABLE IV. Optimized lattice parameters of InSe from DFT calculations

Phase	a (Å)	c (Å)	\bar{c} (Å)	Method / XC	Ref.	Year
γ	4.01	24.56	8.187	WIEN97 / LDA	30	2002
γ	4.02	24.42	8.140	PW(E) / LDA	30	2002
γ	3.99	23.59	7.863	PW(p) / LDA	30	2002
γ	4.01	23.93	7.98	SIESTA / LDA	30	2002
γ	3.953	24.138	8.046	<i>ab initio</i> / LDA	31	2004
β	3.97	16.45	8.225	Quant.Espr. / LDA	21	2014
γ	3.99	25.31	8.437	VASP / PBE+D2	32	2015
γ	3.95	16.92	8.46	VASP / PBE+D2	32	2015
β	4.029	17.615	8.808	WIEN2k / PBE	33	2016
ε	4.036	16.70	8.35	WIEN2k / PBE	33	2016

TABLE V. Band gap values E_g in GaSe from experiments and GW calculations

Phase	direct/indirect	E_g (eV)	comment	Ref.	Year
β	direct	2.169 ± 0.002		34	1969
(γ, ε)	direct	2.120 ± 0.002		34	1969
β	indirect	2.117		34	1969
(γ, ε)	indirect	2.065		34	1969
β	direct	2.050	exciton peak	35	1975
δ	direct	2.026	exciton peak	35	1975
ε	direct	2.004	exciton peak	35	1975
(γ, ε)	direct	2.0196		36	1989
(γ, ε)	indirect	2.010		36	1989
ε	indirect	1.995		37	2006
ε	direct	2.020	at 300 K	37	2006
ε	direct	2.34	GW	16	2011
ε	direct	1.75	GW ($\Gamma - \Gamma$)	16	2011
ε	direct	1.99	GW ($M - \Gamma$)	16	2011
ε	direct	1.93	G_0W_0	38	2014
ε	direct	2.11	G_0W_0	38	2014

 TABLE VI. Band gap values E_g in InSe from experiments and GW calculations

Phase	direct/indirect	E_g (eV)	comment	Ref.	Year
γ	direct	1.263	(at 293 K)	39	1978
γ	direct	1.3525	(at 1.6 K)	39	1978
γ	direct	~ 1.336	(at 10 K)	40	1992
γ	direct	1.24	from Fig. 4 in Ref. →	41	2001
γ	indirect	1.34	from Fig. 4 in Ref. →	41	2001
γ	direct	1.29		28	2003
γ	direct	1.3	VASP + GW	32	2015
β	direct	1.1	VASP + GW	32	2015

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